

**Amendments to the Claims:**

1. (Currently amended) An integrated mass spectrometer device formed from two multilayer wafers, each wafer having ~~an inner~~ a first layer, ~~an outer~~ second layer and having an insulating layer provided therebetween, the device having a plurality of electrode rods and a plurality of planar electrodes, the electrodes being formed in the first layer and electrode rods being provided in the second layer ~~formed on distinct layers of the wafers, the second layer being dimensioned to receive the electrode rods, the rods being retained in contact with the second layer by the provision of at least one resilient member formed in the second layer.~~
2. (Original) The device as claimed in claim 1 wherein each of the multilayer wafers has three layers which are combined to form a five layer structure.
3. (Currently amended) The device as claimed in claim 1 ~~or 2~~ wherein the electrode rods are mountable in the ~~outer~~ second layers of each wafer.
4. (Cancelled).
5. (Currently amended) The device as claimed in claim ~~[[4]]~~ 1 wherein the at least one resilient member is provided by a spring formed in the wafer.
6. (Currently amended) The device as claimed in claim ~~[[4]]~~ 1 wherein the electrode rods are located by etched features in the ~~outer~~ second layer of the wafer, the features being dimensioned so as to suitably receive a rod, and wherein the resilient members is formed by also etching the second ~~outer~~ layer.
7. (Currently amended) The device as claimed in ~~any preceding~~ claim 1 wherein each of the first and second wafers are patterned with an outer pattern provided on a first side the second layer, and an inner pattern provided on the ~~on a second side~~ first layer.
8. (Currently amended) The device as claimed in claim 7 wherein the patterns provided on the ~~second side~~ first layer provides for ion source and ion collection components of the spectrometer.

9. (Currently amended) The device as claimed in claim ~~7 or 8~~ 6 wherein the insulting layer is provided in regions where the patterns overlap.

10. (Currently amended) The device as claimed in ~~any preceding~~ claim 1 wherein the first and second wafers are bonded to form a monolithic block.

11. (Original) The device as claimed in claim 10 wherein the bonding of the first and second wafers is effected such that the electrode rods are located on an outer portion of the block and the electrodes in an inner portion of the block.

12. (Currently amended) The device as claimed in ~~any preceding~~ claim 1 wherein the electrode rods form a mass filter component of the mass spectrometer.

13. (Original) The device as claimed in claim 12 including four cylindrical electrode rods, each rod having its diameter and centre-to-centre separation correctly chosen for quadrupole operation.

14. (Currently amended) The device as claimed in claim ~~12 or 13~~ wherein the horizontal separation of the cylindrical electrodes within each wafer is defined by lithography and deep reactive ion etching.

15. (Currently amended) The device as claimed in ~~any one of claims 12 to 15~~ 12 wherein the vertical separation of the cylindrical electrodes is defined by the combined thickness of the two bonded wafers.

16. (Currently amended) The device as claimed in ~~any preceding~~ claim 1 wherein at least some of the plurality of electrodes are adapted to form ion entrance optics.

17. (Original) The device as claimed in claim 16 wherein the ion entrance optics are formed by an einzel lens.

18. (Original) The device as claimed in claim 16 further including a cold cathode field emission electron source provided in front of the ion entrance optics.

19. (Original) The device as claimed in claim 16 further including an electron source selected from one of:

- a) a hot-cathode source,
- b) a DC discharge source,
- c) an AC discharge source,
- d) an electrospray source.

20. (Original) The device as claimed in claim 16 wherein a pair of RF electrodes are placed in front of the ion entrance optics in order to create a plasma.

21. (Original) The device as claimed in claim 16 wherein the ion entrance optics are formed from an etched fluid channel combined with a set of electrodes that together define an electrospray source.

22. (Currently amended) The device as claimed in ~~any preceding~~ claim 1 wherein each of the wafers are bonded silicon on insulator wafers.

23. (Currently amended) The device as claimed in ~~any preceding~~ claim 1 further including two or more distinct chambers, the provision of distinct chambers enabling the use of the device within a differentially pumped system.

24. (Currently amended) The device as claimed in ~~any preceding~~ claim 1 further including an ion source provided in a mesh configuration.

25. (Currently amended) The device as claimed in ~~any preceding~~ claim 1 wherein at least some of the plurality of electrodes are arranged in a mesh configuration.

26. (Currently amended) The device as claimed in ~~any one of claims 1 to 23~~ claim 1 wherein at least some of the plurality of electrodes are arranged in a tube arrangement.

27. (Original) The device as claimed in claim 26 wherein the tube arrangement provides a lens located at at least one of the entrance or exit to the electrode rods.

28. (Currently amended) The device as claimed in ~~any preceding~~ claim 1 wherein at least some of the plurality of electrode rods are configured as ion reflectors.

29. (Original) The device as claimed in claim 28 wherein the ion reflectors are configured to provide a linear ion trap.

30. (Currently amended) The device as claimed in ~~any preceding~~ claim 1 further including a filament element adapted to provide a source of electrons, the filament element being configured as one of the following types:

- a) an externally provided filament,
- b) an integrally formed filament, or
- c) a removable filament.

31. (Original) A mass spectrometer system including a device as claimed in claim 1 in combination with an ion source and/or an ion detector, at least one of the ion source and/or ion detector being provided externally to the device.

32. (Currently amended) A mass spectrometer array comprising a plurality of devices as ~~claimed in any preceding claim, each device being an integrated mass spectrometer device~~ formed from two multilayer wafers, each wafer having a first layer, a second layer and having an insulating layer provided therebetween, the device having a plurality of electrode rods and a plurality of planar electrodes, the electrodes being formed in the first layer and electrode rods being provided in the second layer, the second layer being dimensioned to receive the electrode rods, the rods being retained in contact with the second layer by the provision of at least one resilient member formed in the second layer.

33. (Currently amended) A mass spectrometer system ~~comprising two or more devices as claimed in any one of claims 1 to 30, according to claim 32 comprising two or more devices,~~ the two or more devices being provided in series so as to form a tandem mass spectrometer.

34. (Original) A mass spectrometer system as claimed in claim 33, wherein each of the devices forming the series of devices is a quadrupole device and wherein a pair of RF electrodes are placed between the cascaded quadrupole devices in order to create a plasma.

39. . A method as claimed in claim 37 wherein the diaphragm electrode arrangement is provided in the form of a three- electrode configuration, inner and outer electrodes of the three electrode configuration being configured to operate at the same potential.